

Major Ratings and Characteristics

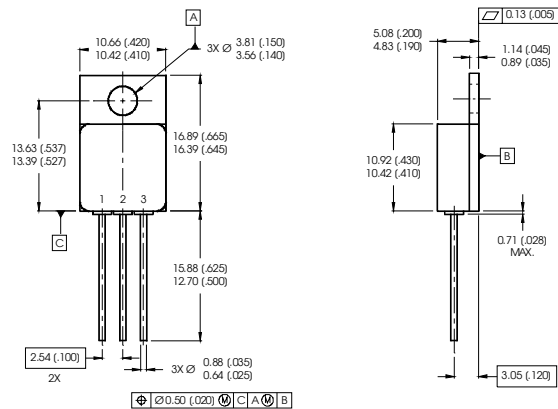
Characteristics	1N7070CCT3	Units
$I_{F(AV)}$	16	A
V_{RRM} (Per Leg)	100	V
I_{FSM} @ $t_p = 8.3ms$ half-sine (Per Leg)	250	A
V_F @ 16Apk, $T_J = 125^\circ C$ (Per Leg)	0.85	V
T_J, T_{stg} Operating and storage	-65 to 150	$^\circ C$

Description/Features

The 1N7070CCT3 center tap Schottky rectifier has been expressly designed to meet the rigorous requirements of high reliability environments. It is packaged in the hermetic isolated TO-257AA package. The device's forward voltage drop and reverse leakage current are optimized for the lowest power loss and the highest circuit efficiency for typical high frequency switching power supplies and resonant power converters. Full MIL-PRF-19500 quality conformance testing is available on source control drawings to TX, TXV and S quality levels.

- Hermetically Sealed
- Ceramic Eyelets
- Low Forward Voltage Drop
- High Frequency Operation
- Guard Ring for Enhanced Ruggedness and Long term Reliability
- Lightweight
- ESD Rating: Class NS per MIL-STD-750, Method 1020

CASE STYLE



Case Outline and Dimensions - TO-257AA

Voltage Ratings

	Part number	1N7070CCT3
V _R	Max. DC Reverse Voltage (V) (Per Leg)	100
V _{RWM}	Max. Working Peak Reverse Voltage (V) (Per Leg)	

Absolute Maximum Ratings

	Parameters	Limits	Units	Conditions
I _{F(AV)}	Max. Average Forward Current See Fig. 5	16	A	50% duty cycle @ T _C = 110°C, square waveform
I _{FSM}	Max. Peak One Cycle Non - Repetitive Surge Current (Per Leg)	250	A	@ t _p = 8.3 ms half-sine

Electrical Specifications

	Parameters	Limits	Units	Conditions	
V _{FM}	Max. Forward Voltage Drop (Per Leg) See Fig. 1 ①	0.77	V	@ 8.0A	T _J = -55°C
		0.98	V	@ 16A	
		0.75	V	@ 8.0A	T _J = 25°C
		0.95	V	@ 16A	
		0.66	V	@ 8.0A	T _J = 125°C
		0.85	V	@ 16A	
I _{RM}	Max. Reverse Leakage Current (Per Leg) See Fig. 2 ①	0.01	mA	T _J = 25°C	V _R = rated V _R
		10	mA	T _J = 125°C	
C _T	Max. Junction Capacitance (Per Leg)	430	pF	V _R = 5V _{DC} (1MHz, 25°C)	
L _S	Typical Series Inductance (Per Leg)	7.8	nH	Measured from anode lead to cathode lead 6mm (0.025 in.) from package	

Thermal-Mechanical Specifications

	Parameters	Limits	Units	Conditions
T _J	Max. Junction Temperature Range	-65 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-65 to 150	°C	
R _{thJC}	Max. Thermal Resistance, Junction to Case (Per Leg)	2.0	°C/W	DC operation See Fig. 4
R _{thJC}	Max. Thermal Resistance, Junction to Case (Per Package)	1.0	°C/W	DC operation
wt	Weight (Typical)	4.3	g	
	Die Size (Typical)	105 X125	mils	
	Case Style	T0-257AA		

① Pulse Width < 300μs, Duty Cycle < 2%

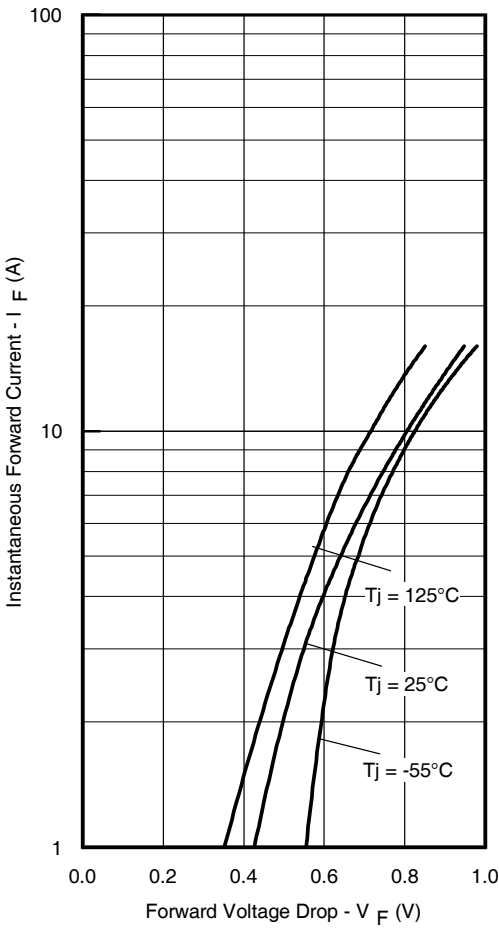


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

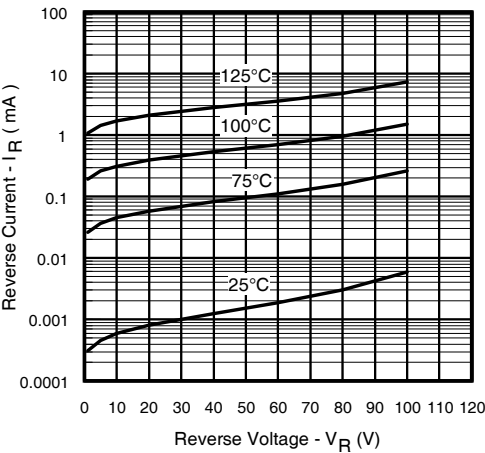


Fig. 2 - Typical Reverse Current Vs. Reverse Voltage (Per Leg)

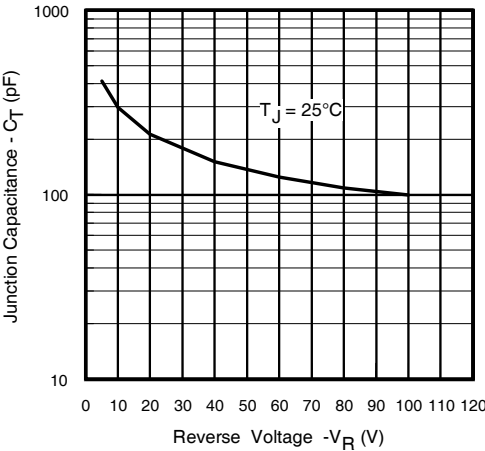
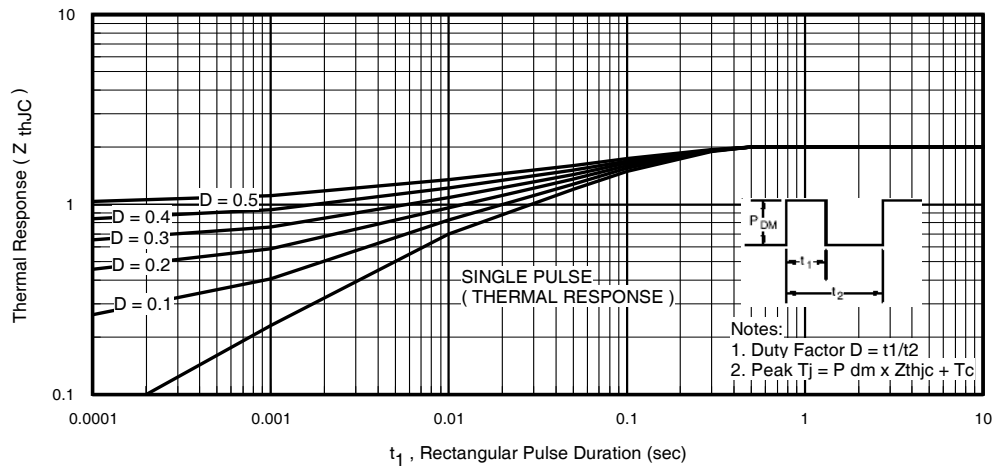
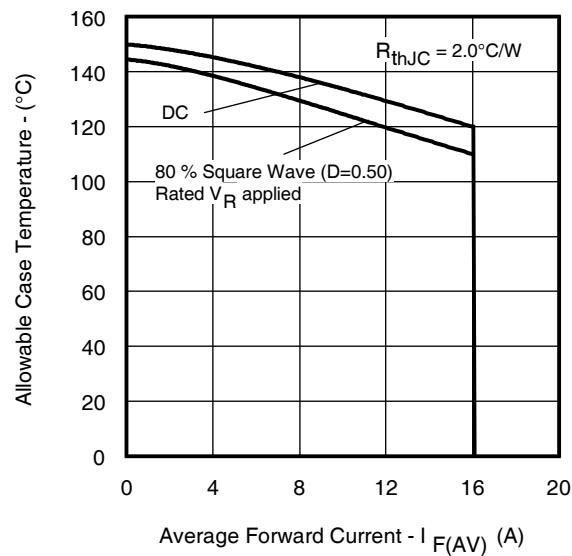


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)Fig. 5 - Max. Allowable Case Temperature Vs.
Average Forward Current (Per Leg)